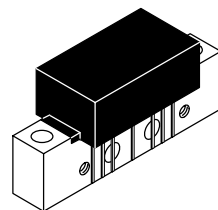


Replaced by MHW8267AN. There are no form, fit or function changes with this part replacement. N suffix indicates RoHS compliant part.

MHW8267A

870 MHz
27.6 dB GAIN
112-CHANNEL
GaAs CATV AMPLIFIER MODULE



CASE 1302-01, STYLE 1

Gallium Arsenide CATV Amplifier Module

Features

- Specified for 79- and 112-Channel Loading
- Excellent Distortion Performance
- Higher Output Capability
- Built-in Input Diode Protection
- GaAs FET Transistor Technology
- Unconditionally Stable Under All Load Conditions
- Output Port Ring Wave Protection

Applications

- CATV Systems Operating in the 47 to 870 MHz Frequency Range
- Output Stage Amplifier in Optical Nodes, Line Extenders and Trunk Distribution Amplifiers for CATV Systems
- Driver Amplifier in Linear General Purpose Applications

Description

- 24 Vdc Supply, 47 to 870 MHz, CATV GaAs Forward Power Doubler Amplifier Module

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V_{in}	+70	dBmV
DC Supply Voltage	V_{CC}	+26	Vdc
Operating Case Temperature Range	T_C	-20 to +100	°C
Storage Temperature Range	T_{stg}	-40 to +100	°C

Table 2. ESD Maximum Ratings

Rating	Input Value	Output Value	Unit
Surge Voltage per IEC 1000-4-5	200	200	V
Human Body Model per Mil. Std. 1686	2	2	kV

Table 3. Electrical Characteristics ($V_{CC} = 24$ Vdc, $T_C = +45^\circ\text{C}$, 75 Ω system unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Frequency Range	BW	40	—	870	MHz
Power Gain 870 MHz	G_p	27	27.6	28.2	dB
Slope 47-870 MHz	S	0	0.7	1.4	dB
Gain Flatness (40-870 MHz, Peak-to-Valley)	G_F	—	—	0.7	dB
Return Loss — Input ($Z_o = 75$ Ohms)	IRL	20	—	—	dB
		18	—	—	
		16	—	—	

ARCHIVE INFORMATION

ARCHIVE INFORMATION

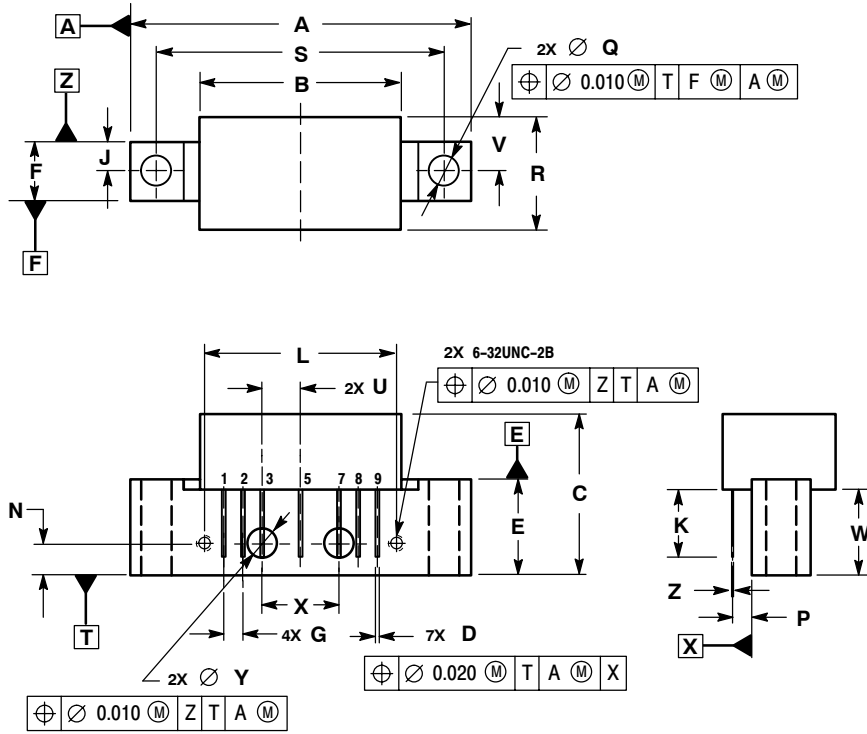
Table 3. Electrical Characteristics ($V_{CC} = 24$ Vdc, $T_C = +45^\circ\text{C}$, 75Ω system unless otherwise noted) (continued)

Characteristic	Symbol	Min	Typ	Max	Unit
Return Loss — Output ($Z_o = 75$ Ohms) 47-160 MHz f > 160-700 MHz f > 701-870 MHz	ORL	20 18 16	— — —	— — —	dB
Composite Second Order ($V_{out} = +48$ dBmV/ch., Worst Case) 112-Channel FLAT ($V_{out} = +48$ dBmV/ch., Worst Case) 79-Channel FLAT ($V_{out} = +56$ dBmV @ 870 MHz Equiv) 112-Channel, 12db Tilt ($V_{out} = +58$ dBmV @ 870 MHz Equiv) 79-Channel, 12db Tilt	CSO_{112} CSO_{79} CSO_{112} CSO_{79}	— — — —	-64 -68 -64 -69	-62 -66 -62 -67	dBc
Cross Modulation Distortion @ Ch 2 ($V_{out} = +48$ dBmV/ch., FM = 55 MHz) 112-Channel FLAT ($V_{out} = +48$ dBmV/ch., FM = 55 MHz) 79-Channel FLAT ($V_{out} = +56$ dBmV @ 870 MHz Equiv) 112-Channel, 12db Tilt ($V_{out} = +58$ dBmV @ 870 MHz Equiv) 79-Channel, 12db Tilt	XMD_{112} XMD_{79} XMD_{112} XMD_{79}	— — — —	-57 -59 -52 -55	-55 -57 -50 -52	dBc
Composite Triple Beat ($V_{out} = +48$ dBmV/ch., Worst Case) 112-Channel FLAT ($V_{out} = +48$ dBmV/ch., Worst Case) 79-Channel FLAT ($V_{out} = +56$ dBmV @ 870 MHz Equiv) 112-Channel, 12db Tilt ($V_{out} = +58$ dBmV @ 870 MHz Equiv) 79-Channel, 12db Tilt	CTB_{112} CTB_{79} CTB_{112} CTB_{79}	— — — —	-59 -66 -57 -62	-57 -64 -55 -60	dBc
Noise Figure 50 MHz 550 MHz 750 MHz 870 MHz	NF	— — — —	5.5 5.5 5.8 6.0	— — — —	dB
DC Current ($V_{DC} = 24$ V, $T_C = 45^\circ\text{C}$)	I_{DC}	410	440	460	mA

ARCHIVE INFORMATION

ARCHIVE INFORMATION

PACKAGE DIMENSIONS



- NOTES:
 1. DIMENSIONS ARE IN INCHES.
 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	---	1.775	---	45.085
B	---	1.085	---	27.559
C	---	0.840	---	21.336
D	0.015	0.021	0.381	0.533
E	0.465	0.510	11.811	12.954
F	0.300	0.325	7.62	8.255
G	0.100 BSC		2.540 BSC	
J	0.156 BSC		3.962 BSC	
K	0.315	0.355	8.001	9.017
L	1.000 BSC		25.400 BSC	
N	0.165 BSC		4.191 BSC	
P	0.100 BSC		2.540 BSC	
Q	0.148	0.168	3.759	4.267
R	---	0.600	---	15.24
S	1.500 BSC		38.100 BSC	
U	0.200 BSC		5.080 BSC	
V	---	0.250	---	6.350
W	0.435	---	11.049	---
X	0.400 BSC		10.160 BSC	
Y	0.152	0.163	3.861	4.140
Z	0.009	0.011	0.229	0.279

- STYLE 1:
 PIN 1. RF INPUT
 2. GROUND
 3. GROUND
 4. DELETED
 5. VDC
 6. DELETED
 7. GROUND
 8. GROUND
 9. RF OUTPUT

CASE 1302-01
 ISSUE B

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